

P-Channel Power MOSFET

-20V, -6.4A, 40mΩ

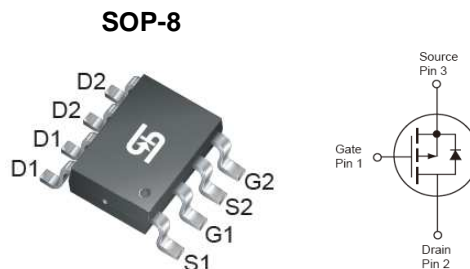
Features

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

Application

- Load Switch
- PA Switch

| KEY PERFORMANCE PARAMETERS | | |
|----------------------------|------------------|------|
| PARAMETER | VALUE | UNIT |
| V_{DS} | -20 | V |
| $R_{DS(on)}$ (max) | $V_{GS} = -10V$ | 40 |
| | $V_{GS} = -4.5V$ | 60 |
| Q_g | 19 | nC |



Notes: Moisture sensitivity level: level 3. Per J-STD-020

| ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ C$ unless otherwise noted) | | | |
|---|----------------|---------------------|------------|
| PARAMETER | SYMBOL | LIMIT | UNIT |
| Drain-Source Voltage | V_{DS} | -20 | V |
| Gate-Source Voltage | V_{GS} | ± 8 | V |
| Continuous Drain Current ^(Note 1) | I_D | $T_C = 25^\circ C$ | -6.4 |
| | | $T_C = 100^\circ C$ | -3.8 |
| Pulsed Drain Current ^(Note 2) | I_{DM} | -19.2 | A |
| Total Power Dissipation @ $T_A = 25^\circ C$ | P_{DTOT} | 2.5 | W |
| Single Pulsed Avalanche Energy ^(Note 3) | E_{AS} | 13.94 | mJ |
| Single Pulsed Avalanche Current ^(Note 3) | I_{AS} | 16.7 | A |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | - 55 to +150 | $^\circ C$ |

| THERMAL PERFORMANCE | | | |
|--|-----------------|-------|--------------|
| PARAMETER | SYMBOL | LIMIT | UNIT |
| Junction to Case Thermal Resistance | $R_{\theta JC}$ | 30 | $^\circ C/W$ |
| Junction to Ambient Thermal Resistance | $R_{\theta JA}$ | 50 | $^\circ C/W$ |

Notes: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case thermal reference is defined at the solder mounting surface of the drain pins. $R_{\theta JA}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design. $R_{\theta JA}$ shown below for single device operation on FR-4 PCB in still air.

| ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted) | | | | | | |
|---|--|--------------|------|------|-----------|------------|
| PARAMETER | CONDITIONS | SYMBOL | MIN | TYP | MAX | UNIT |
| Static (Note 4) | | | | | | |
| Drain-Source Breakdown Voltage | $V_{GS} = 0V, I_D = -250\mu A$ | BV_{DSS} | -20 | -- | -- | V |
| Gate Threshold Voltage | $V_{DS} = V_{GS}, I_D = -250\mu A$ | $V_{GS(TH)}$ | -0.4 | -- | -1.0 | V |
| Gate Body Leakage | $V_{GS} = \pm 8V, V_{DS} = 0V$ | I_{GSS} | -- | -- | ± 100 | nA |
| Zero Gate Voltage Drain Current | $V_{DS} = -16V, V_{GS} = 0V$ | I_{DSS} | -- | -- | -1 | μA |
| On-State Drain Current | $V_{DS} \leq -5V, V_{GS} = -4.5V$ | $I_{D(ON)}$ | -10 | -- | -- | A |
| Drain-Source On-State Resistance | $V_{GS} = -4.5V, I_D = -6.4A$ | $R_{DS(ON)}$ | -- | 31 | 40 | m Ω |
| | $V_{GS} = -2.5V, I_D = -5.1A$ | | -- | 45 | 60 | |
| Forward Transconductance | $V_{DS} = -9V, I_D = -6.4A$ | g_{fs} | -- | 14 | -- | S |
| Dynamic (Note 5) | | | | | | |
| Total Gate Charge | $V_{DS} = -10V, I_D = -6.4A,$ $V_{GS} = -4.5V$ | Q_g | -- | 12 | 19 | nC |
| Gate-Source Charge | | Q_{gs} | -- | 1.7 | -- | |
| Gate-Drain Charge | | Q_{gd} | -- | 3.3 | -- | |
| Input Capacitance | $V_{DS} = -10V, V_{GS} = 0V,$ $f = 1.0\text{MHz}$ | C_{iss} | -- | 1020 | -- | pF |
| Output Capacitance | | C_{oss} | -- | 191 | -- | |
| Reverse Transfer Capacitance | | C_{rss} | -- | 140 | -- | |
| Gate Resistance | $F = 1\text{MHz}, \text{open drain}$ | R_g | -- | 3 | -- | Ω |
| Switching (Note 6) | | | | | | |
| Turn-On Delay Time | $V_{DD} = -10V,$ $R_{GEN} = 6\Omega,$ $I_D = -1A, V_{GS} = -4.5V,$ | $t_{d(on)}$ | -- | 25 | 40 | ns |
| Turn-On Rise Time | | t_r | -- | 43 | 65 | |
| Turn-Off Delay Time | | $t_{d(off)}$ | -- | 71 | 110 | |
| Turn-Off Fall Time | | t_f | -- | 48 | 75 | |
| Source-Drain Diode (Note 4) | | | | | | |
| Forward On Voltage | $I_S = -2.5A, V_{GS} = 0V$ | V_{SD} | -- | -0.9 | -1.2 | V |
| Reverse Recovery Time | $I_S = -4A$ $dI_F/dt = 100A/\mu s$ | t_{rr} | -- | 12.6 | -- | ns |
| Reverse Recovery Charge | | Q_{rr} | -- | 2.84 | -- | nC |

Notes:

1. Current limited by package
2. Pulse width limited by the maximum junction temperature
3. $L = 0.1\text{mH}, I_{AS} = 16.7A, V_{DD} = 25V, R_G = 25\Omega, \text{Starting } T_J = 25^\circ\text{C}$
4. Pulse test: $PW \leq 300\mu s, \text{duty cycle} \leq 2\%$
5. For DESIGN AID ONLY, not subject to production testing.
6. Switching time is essentially independent of operating temperature.

ORDERING INFORMATION

| PART NO. | PACKAGE | PACKING |
|-----------------|----------------|---------------------|
| TSM9434CS RLG | SOP-8 | 2,500pcs / 13" Reel |

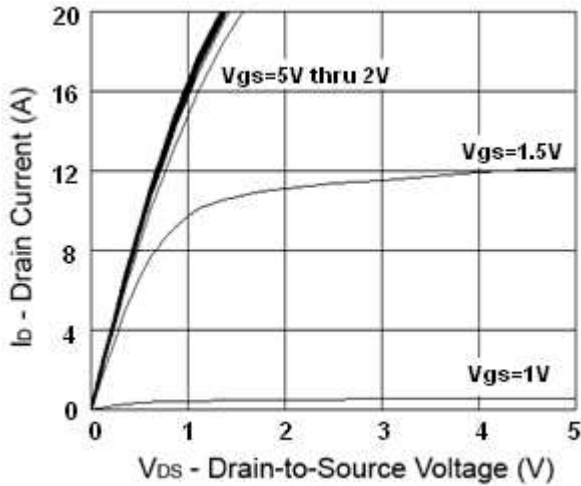
Note:

1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
2. Halogen-free according to IEC 61249-2-21 definition

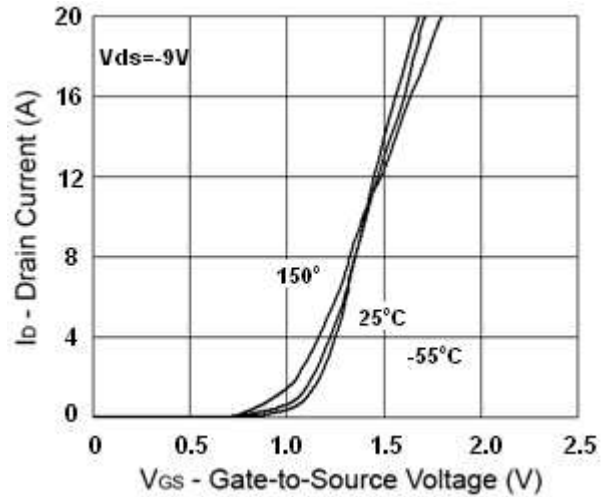
CHARACTERISTICS CURVES

($T_C = 25^\circ\text{C}$ unless otherwise noted)

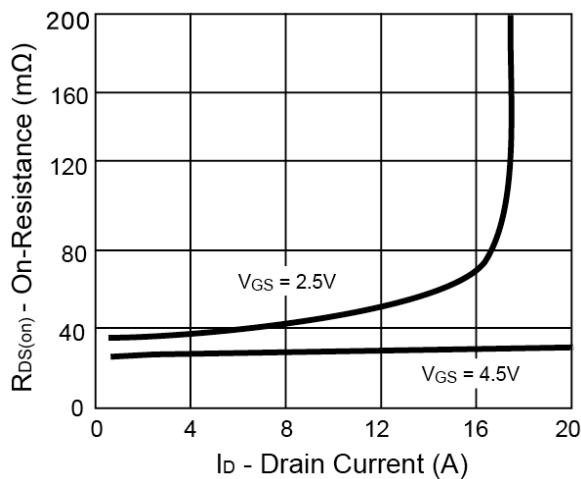
Output Characteristics



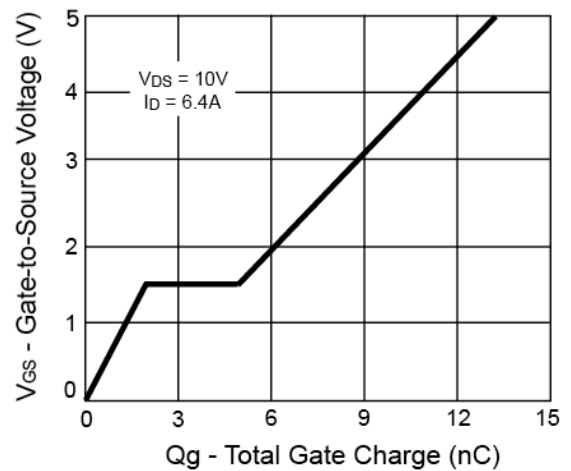
Transfer Characteristics



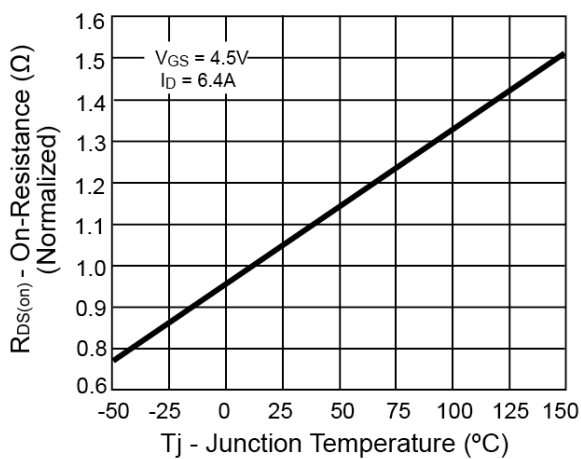
On-Resistance vs. Drain Current



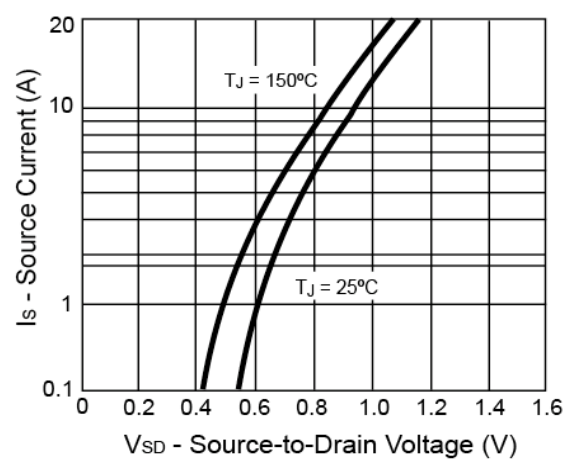
Gate Charge



On-Resistance vs. Junction Temperature



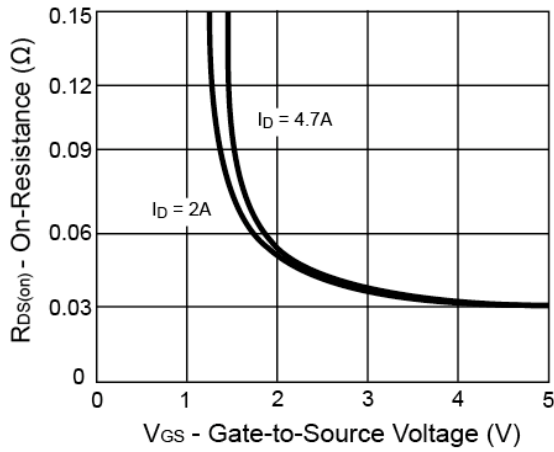
Source-Drain Diode Forward Voltage



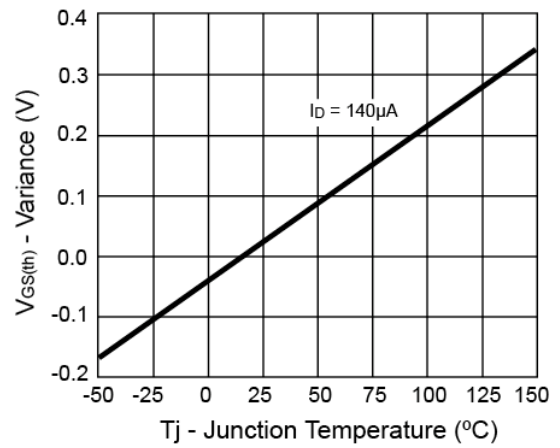
CHARACTERISTICS CURVES

($T_C = 25^\circ\text{C}$ unless otherwise noted)

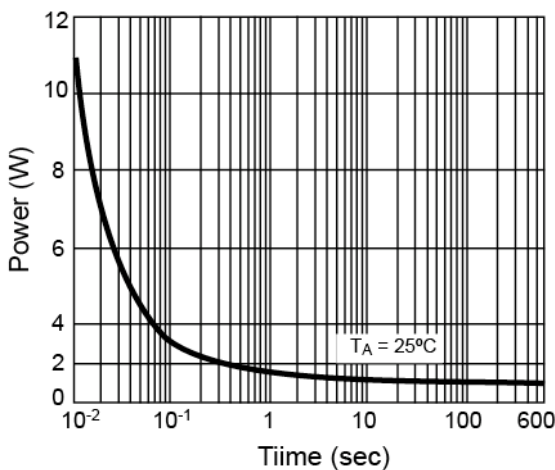
On-Resistance vs. Gate-Source Voltage



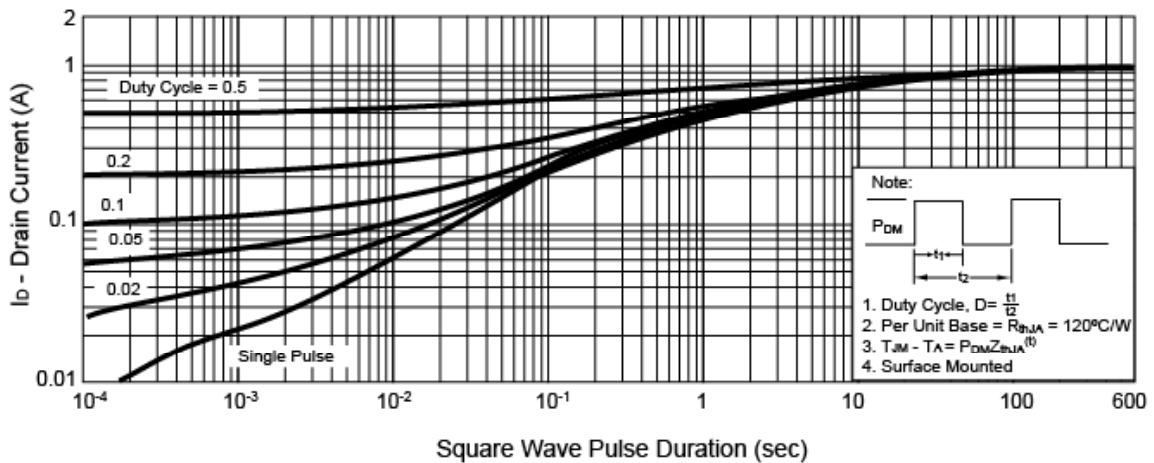
Threshold Voltage



Single Pulse Power

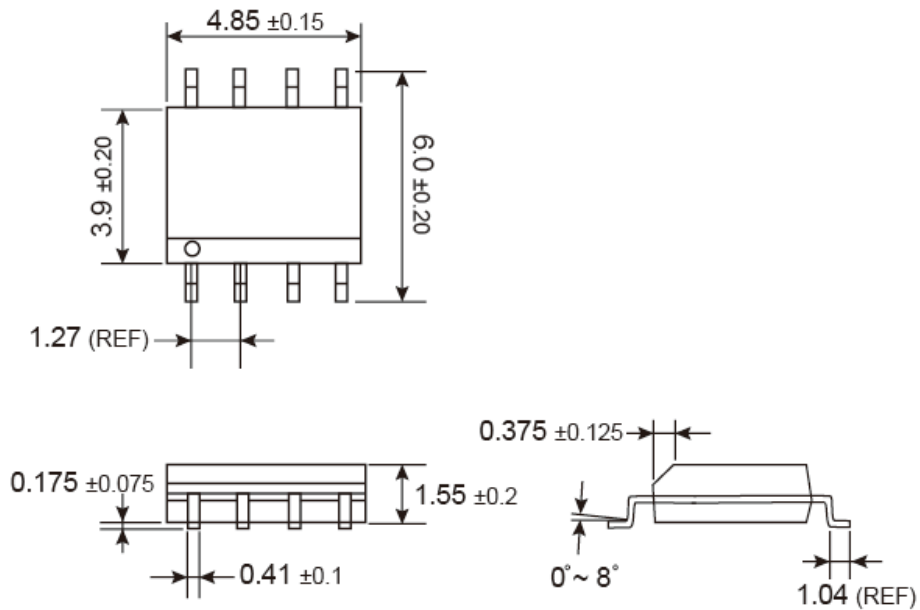


Normalized Thermal Transient Impedance, Junction-to-Ambient

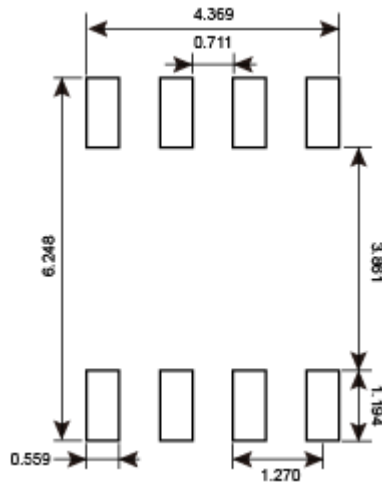


PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

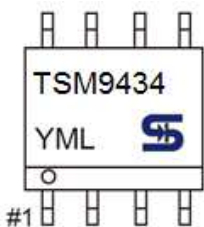
SOP-8



SUGGESTED PAD LAYOUT (Unit: Millimeters)



MARKING DIAGRAM



- Y = Year Code
- M = Month Code for Halogen Free Product
 - O =Jan P =Feb Q =Mar R =Apr
 - S =May T =Jun U =Jul V =Aug
 - W =Sep X =Oct Y =Nov Z =Dec
- L = Lot Code (1~9, A~Z)

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- Поставка образцов и прототипов;
- Техническая поддержка проекта;
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